

**FEATURES**

- Double Side Cooling
- High Reliability In Service
- High Voltage Capability
- Fault Protection Without Fuses
- High Surge Current Capability
- Turn-off Capability Allows Reduction In Equipment Size And Weight. Low Noise Emission Reduces Acoustic Cladding Necessary For Environmental Requirements

**KEY PARAMETERS**

$I_{TCM}$	3000A
$V_{DRM}$	4500V
$I_{T(AV)}$	1100A
$dV_D/dt$	750V/ $\mu$ s
$di_T/dt$	300A/ $\mu$ s

**APPLICATIONS**

- Variable speed A.C. motor drive inverters (VSD-AC).
- Uninterruptable Power Supplies
- High Voltage Converters.
- Choppers.
- Welding.
- Induction Heating.
- DC/DC Converters.

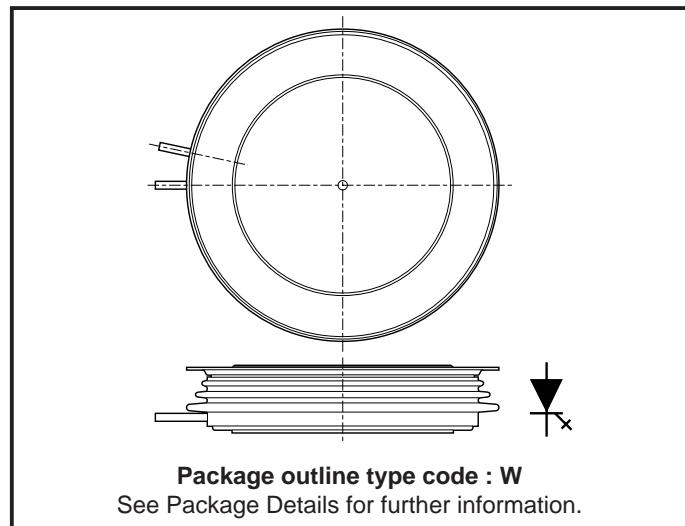


Fig.1 Package outline

**VOLTAGE RATINGS**

Type Number	Repetitive Peak Off-state Voltage $V_{DRM}$	Repetitive Peak Reverse Voltage $V_{RRM}$	Conditions
DG858DW45	4500	16	$T_{vj} = 125^\circ\text{C}$ , $I_{DRM} = 100\text{mA}$ , $I_{RRM} = 50\text{mA}$

**CURRENT RATINGS**

Symbol	Parameter	Conditions	Max.	Units
$I_{TCM}$	Repetitive peak controllable on-state current	$V_D = V_{DRM}$ , $T_j = 125^\circ\text{C}$ , $di_{GQ}/dt = 40\text{A}/\mu\text{s}$ , $C_s = 4.0\mu\text{F}$ , $L_s \leq 200\text{nH}$	3000	A
$I_{T(AV)}$	Mean on-state current	$T_{HS} = 80^\circ\text{C}$ . Double side cooled, half sine 50Hz.	1100	A
$I_{T(RMS)}$	RMS on-state current	$T_{HS} = 80^\circ\text{C}$ . Double side cooled, half sine 50Hz.	1720	A

# DG858DW45

## SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
$I_{TSM}$	Surge (non-repetitive) on-state current	10ms half sine. $T_j = 125^\circ C$	20.0	kA
$I^2t$	$I^2t$ for fusing	10ms half sine. $T_j = 125^\circ C$	$2.0 \times 10^6$	$A^2s$
$di_T/dt$	Critical rate of rise of on-state current	$V_D = 3000V$ , $I_T = 3000A$ , $T_j = 125^\circ C$ $I_{FG} > 40A$ , Rise time < 1.0 $\mu s$	300	$A/\mu s$
$dV_D/dt$	Rate of rise of off-state voltage	To 66% $V_{DRM}$ ; $R_{GK} \leq 22\Omega$ , $T_j = 125^\circ C$	20	$V/\mu s$
		To 66% $V_{DRM}$ ; $V_{RG} = -2V$ , $T_j = 125^\circ C$	750	$V/\mu s$
$L_s$	Peak stray inductance in snubber circuit	$I_T = 3000A$ , $V_D = V_{DRM}$ , $T_j = 125^\circ C$ , $di_{GQ}/dt = 40A/\mu s$ , $C_s = 4.0\mu F$	200	nH

## GATE RATINGS

Symbol	Parameter	Conditions	Min.	Max.	Units
$V_{RGM}$	Peak reverse gate voltage	This value maybe exceeded during turn-off	-	16	V
$I_{FGM}$	Peak forward gate current		20	100	A
$P_{FG(AV)}$	Average forward gate power		-	20	W
$P_{RGM}$	Peak reverse gate power		-	24	kW
$di_{GQ}/dt$	Rate of rise of reverse gate current		20	60	$A/\mu s$
$t_{ON(min)}$	Minimum permissible on time		50	-	$\mu s$
$t_{OFF(min)}$	Minimum permissible off time		100	-	$\mu s$

## THERMAL AND MECHANICAL DATA

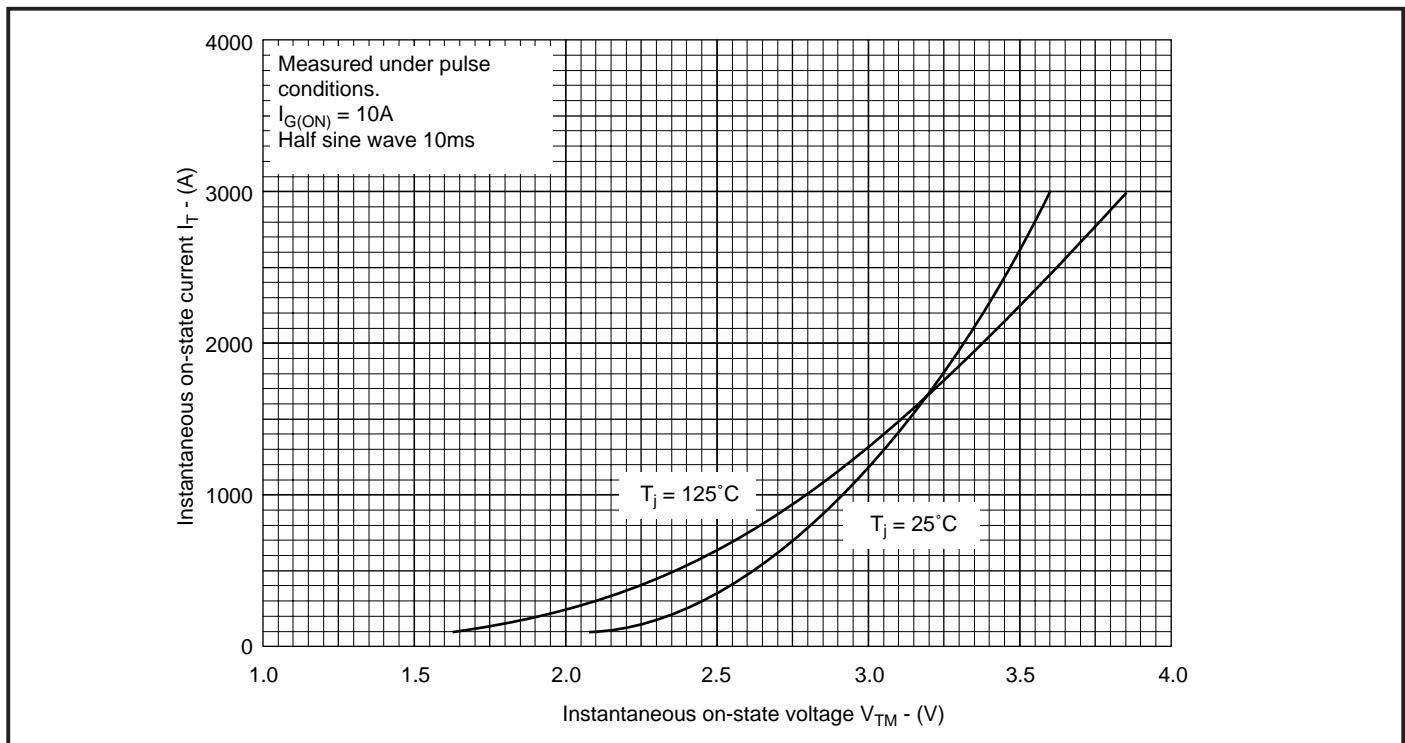
Symbol	Parameter	Conditions	Min.	Max.	Units
$R_{th(j-hs)}$	DC thermal resistance - junction to heatsink surface	Double side cooled	-	0.011	$^\circ C/W$
		Anode side cooled	-	0.017	$^\circ C/W$
		Cathode side cooled	-	0.03	$^\circ C/W$
$R_{th(c-hs)}$	Contact thermal resistance	Clamping force 40kN With mounting compound	per contact	-	$^\circ C/W$
$T_{vj}$	Virtual junction temperature		-40	125	$^\circ C$
$T_{op}/T_{stg}$	Operating junction/storage temperature range		-40	125	$^\circ C$
-	Clamping force		36.0	44.0	kN

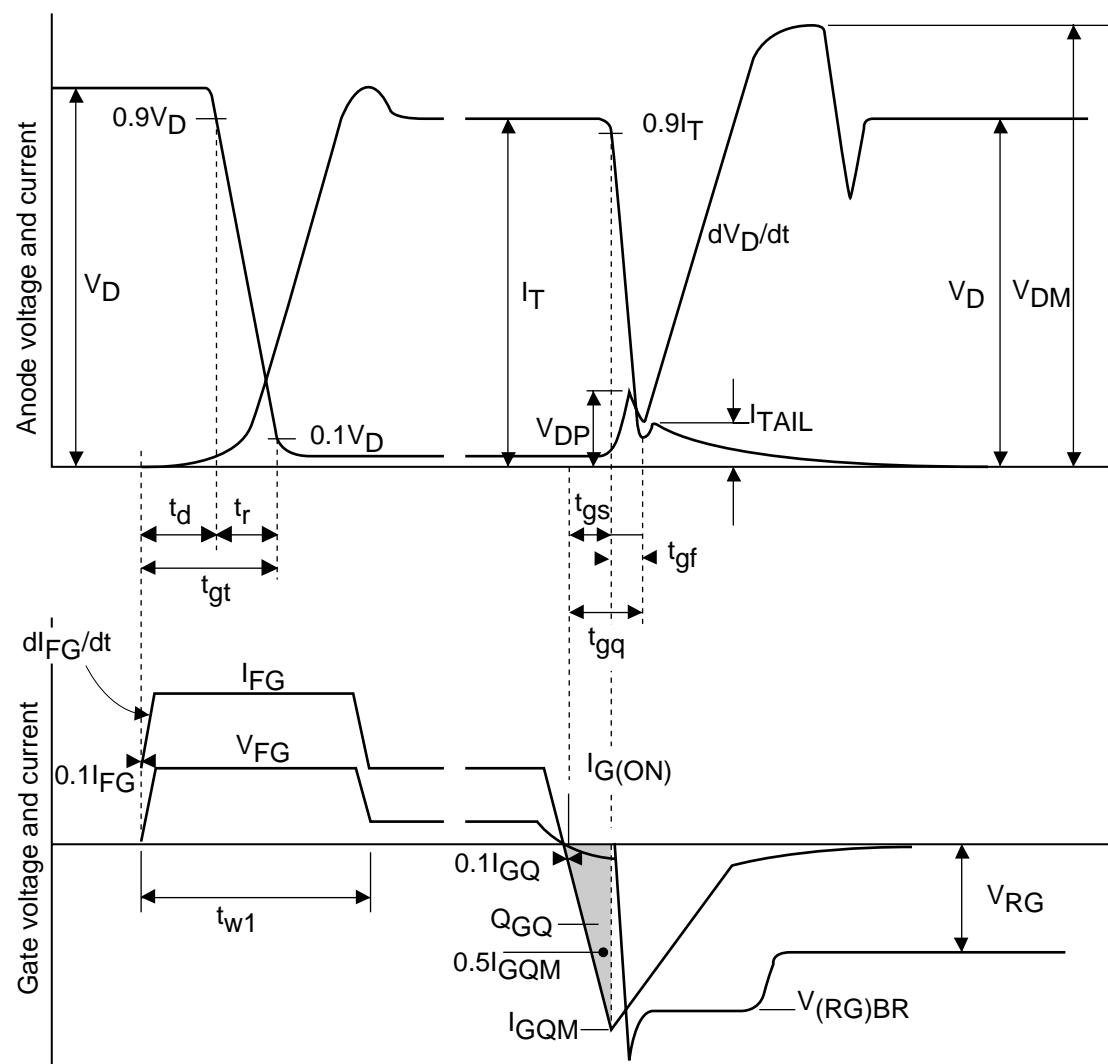
## CHARACTERISTICS

$T_j = 125^\circ\text{C}$ unless stated otherwise						
Symbol	Parameter	Conditions	Min.	Max.	Units	
$V_{TM}$	On-state voltage	At 3000A peak, $I_{G(ON)} = 10\text{A}$ d.c.	-	3.85	V	
$I_{DM}$	Peak off-state current	$V_{DRM} = 4500\text{V}$ , $V_{RG} = 2\text{V}$	-	100	mA	
$I_{RRM}$	Peak reverse current	At $V_{RRM}$	-	50	mA	
$V_{GT}$	Gate trigger voltage	$V_D = 24\text{V}$ , $I_T = 100\text{A}$ , $T_j = 25^\circ\text{C}$	-	1.2	V	
$I_{GT}$	Gate trigger current	$V_D = 24\text{V}$ , $I_T = 100\text{A}$ , $T_j = 25^\circ\text{C}$	-	4.0	A	
$I_{RGM}$	Reverse gate cathode current	$V_{RGM} = 16\text{V}$ , No gate/cathode resistor	-	50	mA	
$E_{ON}$	Turn-on energy	$V_D = 2000\text{V}$	-	4400	mJ	
$t_d$	Delay time	$I_T = 3000\text{A}$ , $di_T/dt = 300\text{A}/\mu\text{s}$	-	2.0	$\mu\text{s}$	
$t_r$	Rise time	$I_{FG} = 40\text{A}$ , rise time < 1.0 $\mu\text{s}$	-	6.0	$\mu\text{s}$	
$E_{OFF}$	Turn-off energy		-	12500	mJ	
$t_{gs}$	Storage time		-	26	$\mu\text{s}$	
$t_{gf}$	Fall time	$I_T = 3000\text{A}$ , $V_{DM} = 4200\text{V}$	-	2.5	$\mu\text{s}$	
$t_{gq}$	Gate controlled turn-off time	Snubber Cap $C_s = 4.0\mu\text{F}$ ,	-	28.5	$\mu\text{s}$	
$Q_{GQ}$	Turn-off gate charge	$di_{GQ}/dt = 40/\mu\text{s}$	-	12500	$\mu\text{C}$	
$Q_{GQT}$	Total turn-off gate charge		-	25000	$\mu\text{C}$	
$I_{GQM}$	Peak reverse gate current		-	950	A	

## RELIABILITY

	Conditions	Limit	Units
DC blocking reliability	$V_{dc} = 3500\text{V}$ , $T_j = -40$ to $+125^\circ\text{C}$ , ambient cosmic radiation at sea level, in open air, 100% duty cycle.	100	FIT

**CURVES****Figure 2. On-state characteristics**



Recommended gate conditions:

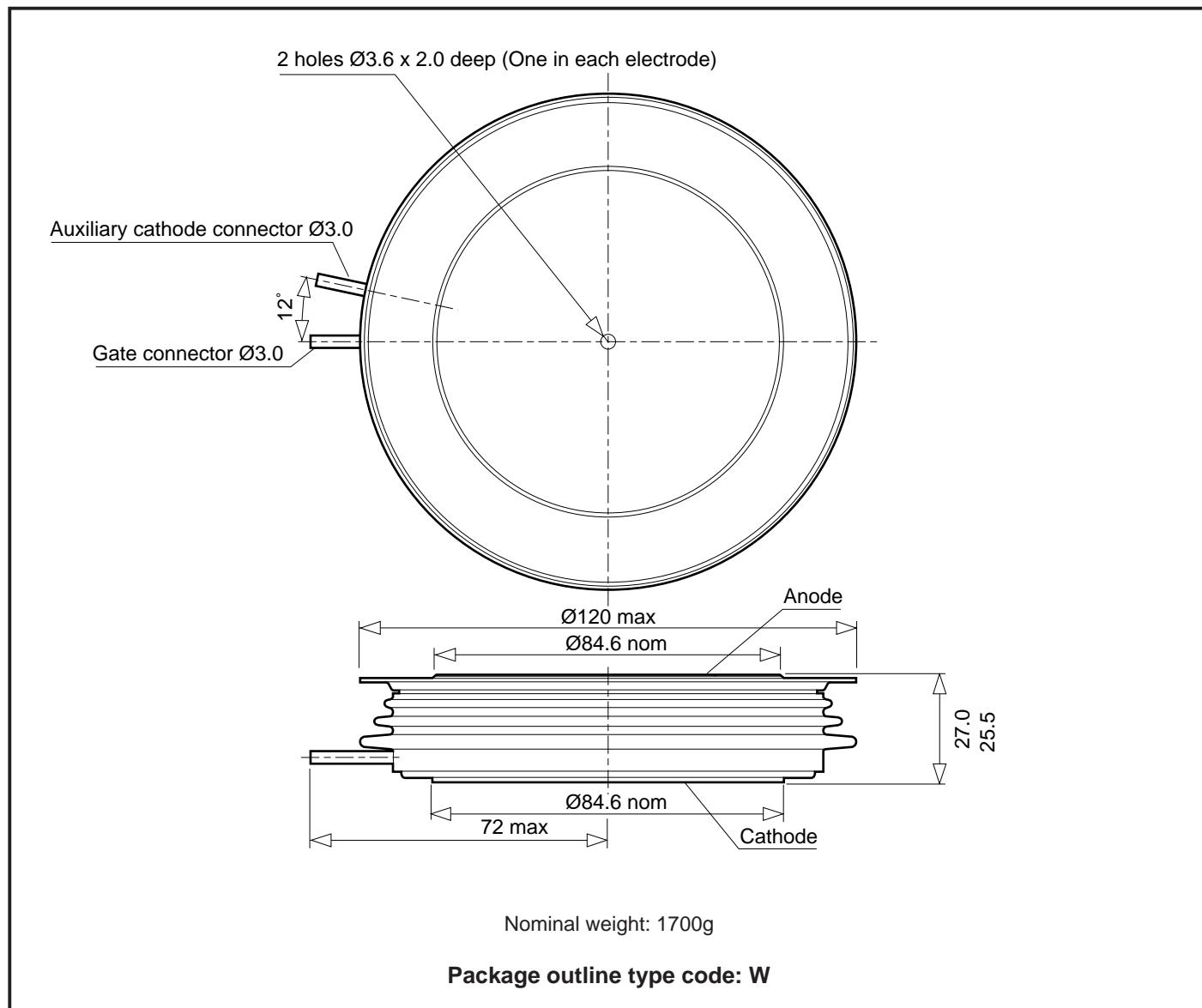
$I_{TCM} = 3000A$   
 $I_{FG} = 40A$   
 $I_{G(ON)} = 10A$  d.c.  
 $t_{w1(min)} = 20\mu s$   
 $I_{GQM} = 1200A$   
 $di_{GQ}/dt = 40A/\mu s$   
 $Q_{GQ} = 12500\mu C$   
 $V_{RG(min)} = 2V$   
 $V_{RG(max)} = 18V$

These are recommended Dynex Semiconductor conditions. Other conditions are permitted according to users gate drive specifications.

Figure 3. General switching waveforms

**PACKAGE DETAILS**

For further package information, please contact your local Customer Service Centre. All dimensions in mm, unless stated otherwise. DO NOT SCALE.

**Associated Literature/Products**

Publication No. Title/Part Number

AN4571	Application note - GDU9X-XXXXX Series GTO gate drive units.
DS4567	GDU90-20721 GTO gate drive unit.
DS4568	GDU90-20722 GTO gate drive unit.
DS4150	DSF8045SK - Snubber diode.
DS4153	DSF21545SV - Antiparallel/freewheel diode.



<http://www.dynexsemi.com>

e-mail: [power\\_solutions@dynexsemi.com](mailto:power_solutions@dynexsemi.com)

HEADQUARTERS OPERATIONS  
**DYNEX SEMICONDUCTOR LTD**  
 Doddington Road, Lincoln.  
 Lincolnshire. LN6 3LF. United Kingdom.  
 Tel: 00-44-(0)1522-500500  
 Fax: 00-44-(0)1522-500550

**DYNEX POWER INC.**  
 Unit 7 - 58 Antares Drive,  
 Nepean, Ontario, Canada K2E 7W6.  
 Tel: 613.723.7035  
 Fax: 613.723.1518  
 Toll Free: 1.888.33.DYNEX (39639)

CUSTOMER SERVICE CENTRES  
**Central Europe** Tel: +33 (0)1 69 18 90 00. Fax: +33 (0)1 64 46 54 50.  
**North America** Tel: 011-800-5554-5554. Fax: 011-800-5444-5444.  
**UK, Scandinavia & Rest Of World** Tel: +44 (0)1522 500500. Fax: +44 (0)1522 500020.

SALES OFFICES  
**Central Europe** Tel: +33 (0)1 69 18 90 00. Fax: +33 (0)1 64 46 54 50.  
**North America** Tel: (613) 723-7035. Fax: (613) 723-1518. Toll Free: 1.888.33.DYNEX (39639) /  
 Tel: (831) 440-1988. Fax: (831) 440-1989 / Tel: (949) 733-3005. Fax: (949) 733-2986.  
**UK, Scandinavia & Rest Of World** Tel: +44 (0)1522 500500. Fax: +44 (0)1522 500020.  
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